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Octal Bidirectional Transceiver with 3-State Inputs/Outputs

The MC74AC245/74ACT245 contains eight non-inverting bidirectional buffers with 3-state outputs and is intended for bus-oriented applications. Current sinking capability is 24 mA at both the A and B ports. The Transmit/Receive (T/\overline{R}) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a High Z condition.

Features

- Noninverting Buffers
- Bidirectional Data Path
- A and B Outputs Source/Sink 24 mA
- 'ACT245 has TTL Compatible Inputs
- These are Pb–Free Devices

PIN ASSIGNMENT

PIN	FUNCTION
ŌĒ	Output Enable Input
T/R	Transmit/Receive Input
A ₀ -A ₇	Side A 3–State Inputs or 3–State Outputs
B ₀ –B ₇	Side B 3–State Inputs or 3–State Outputs

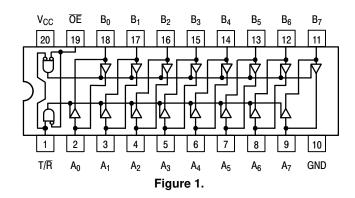
TRUTH TABLES

Inp	uts	Quatravita	
ŌĒ	T/R	Outputs	
L	L	Bus B Data to Bus A	
L	Н	Bus A Data to Bus B	
н	Х	High Z State	

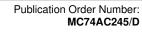
H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial









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SOIC-20W DW SUFFIX CASE 751D



TSSOP-20 DT SUFFIX CASE 948E

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 7 of this data sheet.

MAXIMUM RATINGS

Symbol	Para	meter	Value	Unit	
V _{CC}	DC Supply Voltage (Referenced to GND)		-0.5 to +7.0	V	
V _{IN}	DC Input Voltage (Referenced to GND)	DC Input Voltage (Referenced to GND)			
V _{OUT}	DC Output Voltage (Referenced to GND)	–0.5 to V _{CC} +0.5	V		
I _{IK}	DC Input Diode Current		±20	mA	
I _{OK}	DC Output Diode Current		±50	mA	
I _{OUT}	DC Output Sink/Source Current		±50	mA	
I _{CC}	DC Supply Current, per Output Pin		±50	mA	
I _{GND}	DC Ground Current, per Output Pin	±100	mA		
T _{STG}	Storage Temperature Range	-65 to +150	°C		
ΤL	Lead temperature, 1 mm from Case for 1	0 Seconds	260	°C	
TJ	Junction Temperature Under Bias		140	°C	
θ_{JA}	Thermal Resistance (Note 2)	SOIC TSSOP	65.8 110.7	°C/W	
MSL	Moisture Sensitivity		Level 1		
F _R	Flammability Rating	Oxygen Index: 30% – 35%	UL 94 V–0 @ 0.125 in		
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	> 2000 > 200 > 1000	V	
I _{Latchup}	Latchup Performance Abo	ove V_{CC} and Below GND at 85°C (Note 6)	±100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

I_{OUT} absolute maximum rating must be observed.
 The package thermal impedance is calculated in accordance with JESD 51–7.
 Tested to EIA/JESD22–A114–A.

4. Tested to EIA/JESD22-A115-A.

Tested to JESD22-C101-A. 5.

6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Тур	Max	Unit
M	Cumple Vallage	′AC	2.0	5.0	6.0	V
V _{CC}	Supply Voltage 'ACT		4.5	5.0	5.5	V
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V _{CC}	V
		V _{CC} @ 3.0 V	-	150	-	
t _r , t _f	out Rise and Fall Time (Note 7) C Devices except Schmitt Inputs	V _{CC} @ 4.5 V	-	40	-	ns/V
		V _{CC} @ 5.5 V	-	25	-	
	Input Rise and Fall Time (Note 8)	V _{CC} @ 4.5 V	-	10	-	100 A
t _r , t _f	'ACT Devices except Schmitt Inputs	V _{CC} @ 5.5 V	-	8.0	-	ns/V
T _A	Operating Ambient Temperature Range		-40	25	85	°C
I _{OH}	Output Current – High		-	-	-24	mA
I _{OL}	Output Current – Low			_	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
7. V_{IN} from 30% to 70% V_{CC}; see individual Data Sheets for devices that differ from the typical input rise and fall times.
8. V_{IN} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

	Parameter		74AC		74AC		
Symbol		V _{CC} (V)	T _A = +25°C		T _A = -40°C to +85°C	Unit	Conditions
			Тур	Guar	anteed Limits		
V _{IH}	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V _{IL}	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V _{OH}	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I _{OUT} = -50 μA
		3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	v	$\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ -12 \text{ mA} \\ I_{OH} -24 \text{ mA} \\ -24 \text{ mA} \end{array}$
V _{OL}	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	I _{OUT} = 50 μA
		3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	V	$\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ 12 \text{ mA} \\ I_{OL} \qquad 24 \text{ mA} \\ 24 \text{ mA} \end{array}$
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, GND$
I _{OZT}	Maximum 3-State Current	5.5	-	±0.6	±6.0	μΑ	$V_{I} (OE) = V_{IL}, V_{IH}$ $V_{I} = V_{CC}, GND$ $V_{O} = V_{CC}, GND$
I _{OLD}	†Minimum Dynamic	5.5	-	-	75	mA	$V_{OLD} = 1.65 \text{ V Max}$
I _{OHD}	Output Current	5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	8.0	80.0	μA	$V_{IN} = V_{CC}$ or GND

*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time. NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

				74AC		74	AC		
Symbol	Parameter	V _{CC} * (V)		₄ = +25° cL = 50 p			-40°C 85°C 50 pF	Unit	Fig. No.
			Min	Тур	Max	Min	Max		
t _{PLH}	Propagation Delay A _n to B _n or B _n to A _n	3.3 5.0	1.5 1.5	5.0 3.5	8.5 6.5	1.0 1.0	9.0 7.0	ns	3–5
t _{PHL}	Propagation Delay A _n to B _n or B _n to A _n	3.3 5.0	1.5 1.5	5.0 3.5	8.5 6.0	1.0 1.0	9.0 7.0	ns	3–5
t _{PZH}	Output Enable Time	3.3 5.0	2.5 1.5	7.0 5.0	11.5 8.5	2.0 1.0	12.5 9.0	ns	3–7
t _{PZL}	Output Enable Time	3.3 5.0	2.5 1.5	7.5 5.5	12.0 9.0	2.0 1.0	13.5 9.5	ns	3–8
t _{PHZ}	Output Disable Time	3.3 5.0	2.0 1.5	6.5 5.5	12.0 9.0	1.0 1.0	12.5 10.0	ns	3–7
t _{PLZ}	Output Disable Time	3.3 5.0	2.0 1.5	7.0 5.5	11.5 9.0	1.5 1.0	13.0 10.0	ns	3–8

*Voltage Range 3.3 V is 3.3 V ± 0.3 V. Voltage Range 5.0 V is 5.0 V ± 0.5 V.

DC CHARACTERISTICS

	Parameter		744	СТ	74ACT		
Symbol		V _{CC} (V)	T _A = +25°C		T _A = 40°C to +85°C	Unit	Conditions
			Тур	Guar	anteed Limits		
V _{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	v	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V _{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	v	$\label{eq:VOUT} \begin{array}{l} V_{OUT} = 0.1 \ V \\ \text{or} \ V_{CC} - 0.1 \ V \end{array}$
V _{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	v	I _{OUT} = -50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	v	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} -24 \text{ mA}$ -24 mA
V _{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	v	l _{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	v	$V_{IN} = V_{IL} \text{ or } V_{IH}$ 24 mA I_{OL} 24 mA
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, \text{ GND}$
ΔI_{CCT}	Additional Max. I _{CC} /Input	5.5	0.6	-	1.5	mA	$V_{I} = V_{CC} - 2.1 V$
I _{OZT}	Maximum 3-State Current	5.5	_	±0.6	±6.0	μΑ	
I _{OLD}	†Minimum Dynamic	5.5	-	-	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}	Output Current	5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	8.0	80.0	μΑ	$V_{IN} = V_{CC}$ or GND

*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

74ACT 74ACT $T_A = -40^{\circ}C$ T_A = +25°C V_{CC}* Fig. Symbol Parameter to +85°C Unit $C_L = 50 \text{ pF}$ (V) No. $C_L = 50 \text{ pF}$ Min Тур Мах Min Max Propagation Delay, A_n to B_n or B_n to A_n 5.0 1.5 4.0 7.5 1.5 8.0 ns 3–5 t_{PLH} t_{PHL} Propagation Delay, An to Bn or Bn to An 5.0 1.5 4.0 8.0 1.0 9.0 ns 3–5 Output Enable Time 5.0 1.5 5.0 10 1.5 11.0 ns 3–7 t_{PZH} **Output Enable Time** 5.0 1.5 5.5 10 1.5 12.0 ns 3–8 t_{PZL} **Output Disable Time** 5.0 1.5 5.5 10 1.0 3–7 t_{PHZ} 11.0 ns 2.0 5.0 5.0 10 1.5 11.0 3–8 t_{PLZ} **Output Disable Time** ns

AC CHARACTERISTICS (For Figures and Waveforms – See AND8277/D at www.onsemi.com)

*Voltage Range 5.0 V is 5.0 V \pm 0.5 V.

CAPACITANCE

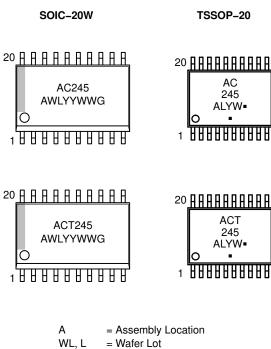
Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{I/O}	Input/Output Capacitance	15	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	45	pF	V _{CC} = 5.0 V

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74AC245DWG	SOIC-20 (Pb-Free)	38 Units / Rail
MC74AC245DWR2G	SOIC-20 (Pb-Free)	1000 / Tape & Reel
MC74ACT245DWG	SOIC-20 (Pb-Free)	38 Units / Rail
MC74ACT245DWR2G	SOIC-20 (Pb-Free)	1000 / Tape & Reel
MC74AC245DTG	TSSOP–20 (Pb–Free)	75 Units / Rail
MC74AC245DTR2G	TSSOP-20 (Pb-Free)	2500 / Tape & Reel
MC74ACT245DTG	TSSOP-20 (Pb-Free)	75 Units / Rail
MC74ACT245DTR2G	TSSOP-20 (Pb-Free)	2500 / Tape & Reel

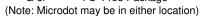
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS

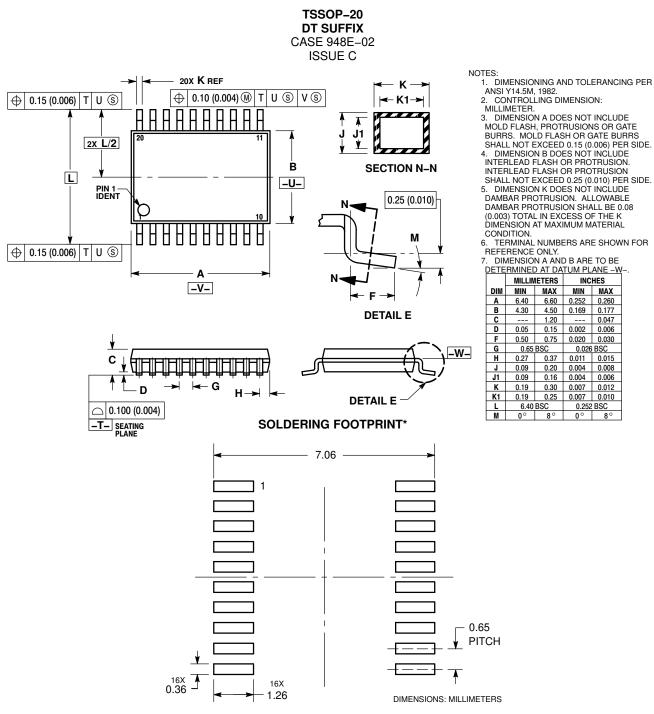


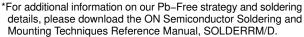
VVL, L	= water Lo
YY, Y	= Year

- WW, W = Work Week
- G or = Pb–Free Package



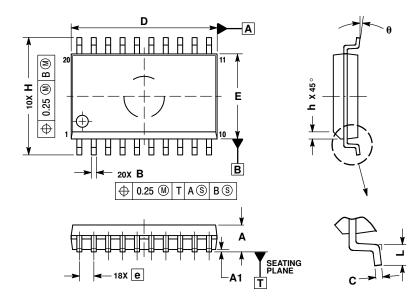
PACKAGE DIMENSIONS





PACKAGE DIMENSIONS

SOIC-20W **DW SUFFIX** CASE 751D-05 **ISSUE G**



NOTES

DIMENSIONS ARE IN MILLIMETERS 1. 2.

- INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994. 3
- DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 PER SIDE. DIMENSION B DOES NOT INCLUDE DAMBAR 5 PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS				
DIM	MIN	MAX			
Α	2.35	2.65			
A1	0.10	0.25			
В	0.35	0.49			
С	0.23	0.32			
D	12.65	12.95			
Е	7.40	7.60			
е	1.27	BSC			
Н	10.05	10.55			
h	0.25	0.75			
L	0.50	0.90			
θ	0 °	7 °			

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